



SSCE3V362N1

1-Line Bidirectional Micro Packaged TVS Diodes for ESD Protection

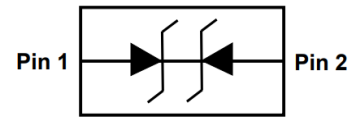
● Description

The SSCE3V362N1 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The SSCE3V362N1 complies with the IEC 61000-4-2 (ESD) with ± 30 kV air and ± 30 kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size and high ESD surge protection make SSCE3V362N1 an ideal choice to protect cell phone, digital cameras, and many other portable applications.

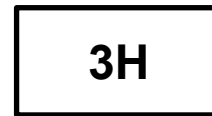
● Feature

- ✧ 480W peak pulse power ($t_P = 8/20\mu s$)
- ✧ DFN1006-2L Package
- ✧ Working voltage: 3.3V
- ✧ Low clamping voltage
- ✧ Low capacitance
- ✧ Low leakage current
- ✧ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ± 30 kV
 - Contact discharge: ± 30 kV
 - IEC61000-4-5 (Lightning) 40A (8/20 μs)
- ✧ RoHS compliant

● PIN configuration



Top view



Marking

● Applications

- ✧ Cellular Handsets and Accessories
- ✧ Notebooks and Handhelds
- ✧ Portable Instrumentation
- ✧ Digital Cameras
- ✧ Peripherals
- ✧ Audio Players
- ✧ Keypads, Side Keys, USB, LCD Displays

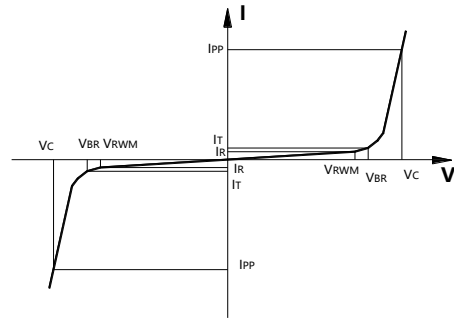
● Mechanical data

- ✧ Lead finish: 100% matte Sn(Tin)
- ✧ Case Material: "Green" Molding Compound
- ✧ Qualified max reflow temperature: 260°C
- ✧ Device meets MSL 3 requirements
- ✧ Pure tin plating: 7 ~ 17 μm
- ✧ Pin flatness: ≤ 3 mil



● Electronic Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power



● Absolute maximum rating @ $T_A=25^\circ\text{C}$

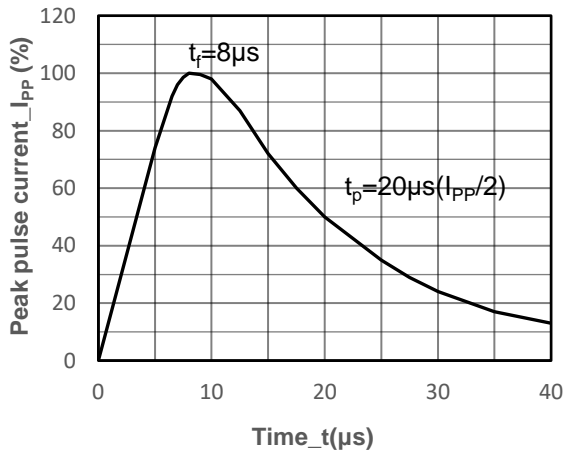
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	P_{PP}	480	W
Peak Pulse Current (8/20 μs)	I_{PP}	40	A
ESD Rating per IEC61000-4-2:	Contact	30	kV
	Air	30	
Storage Temperature	T_{STG}	-55/+150	$^\circ\text{C}$
Operating Temperature	T_J	-55/+125	$^\circ\text{C}$

● Electrical Characteristics @ $T_A=25^\circ\text{C}$

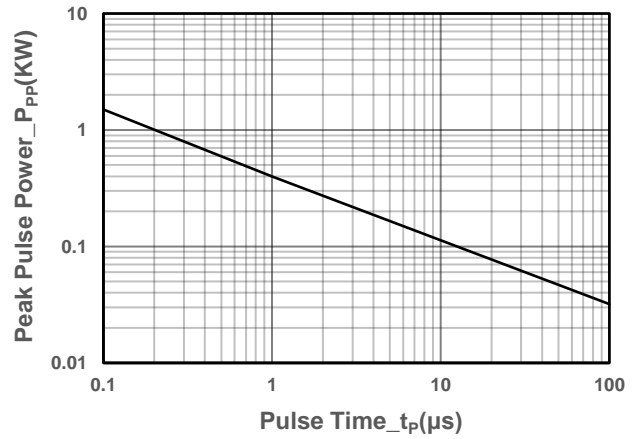
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Working Voltage	V_{RWM}				3.3	V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	3.8		6.2	V
Reverse Leakage Current	I_R	$V_{RWM} = 3.3\text{V}$			0.1	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_P = 8/20\mu\text{s}$		6		V
Clamping Voltage	V_C	$I_{PP} = 40\text{A}$, $t_P = 8/20\mu\text{s}$		8.5	12	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$		100	130	pF



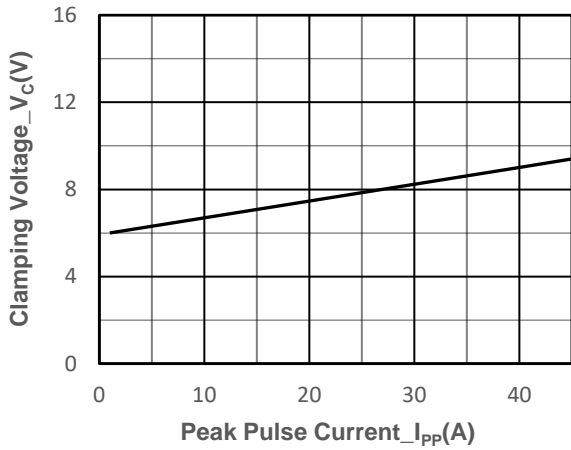
● Typical Performance Characteristics



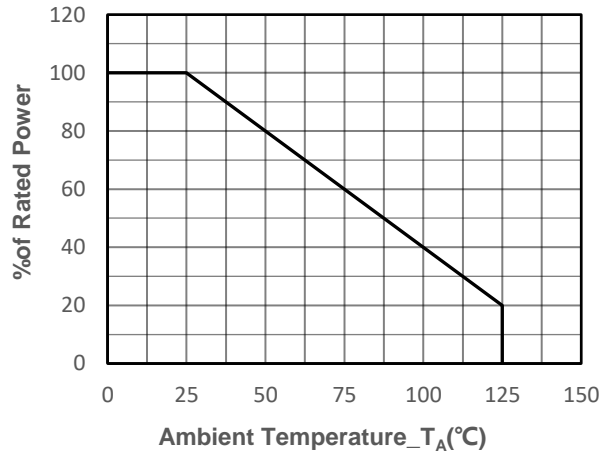
8/20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current



Power derating vs. Ambient temperature



● Package Information

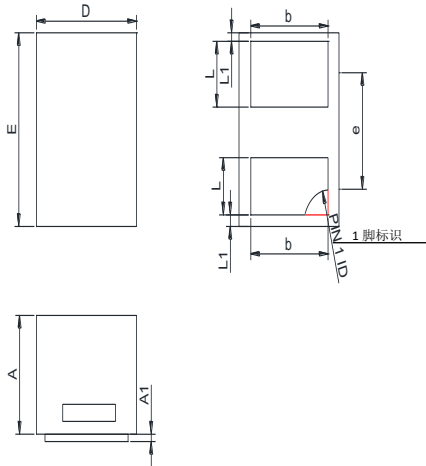
Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCE3V362N1	DFN1006-2L	10000	7 Inch

Mechanical Data

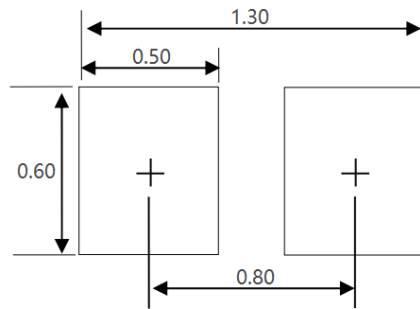
Case:DFN1006-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters	
	Min	Max
A	0.45	0.55
A1	0.00	0.05
D	0.55	0.65
E	0.95	1.05
b	0.45	0.60
e	0.65TYP	
L	0.2	0.3
L1	0.05REF	

Recommended Pad outline



Unit:mm



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